

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









0.8 A sensitive gate SCRs

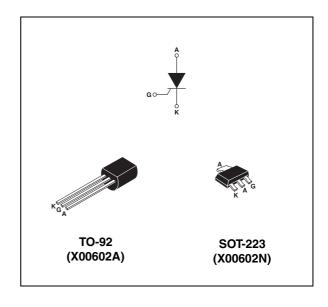
Features

- I_{T(RMS)} = 0.8 A
- $V_{DRM}/V_{RRM} = 600 V$
- I_{GT} = 200 µA

Description

Thanks to highly sensitive triggering levels, the X006 SCR series is suitable for all applications where the available gate current is limited, such as ground fault circuit interrupters, overvoltage crowbar protection in low power supplies, capacitive ignition circuits, etc.

Available in though-hole or surface-mount packages, these devices are optimized in forward voltage drop and inrush current capabilities, for reduced power losses and high reliability in harsh environments.



Characteristics X006

1 Characteristics

Table 1. Absolute ratings (limiting values)

Symbol	Parameter			Value	Unit
1	RMS on-state current (180 °Conduction angle)	TO-92	T _I = 85 °C	0.8	А
IT(RMS)		SOT-223	T _{tab} = 100 °C		
IT.	Average on state current (190 °Conduction angle)	TO-92	T _I = 85 °C 0.5		^
IT _(AV)	Average on-state current (180 °Conduction angle)	SOT-223	T _{tab} = 100 °C	0.5	Α
I	Non repetitive surge peak on-state current	$t_p = 8.3 \text{ ms}$	- T _j = 25 °C	10	Α
I _{TSM}	Non repetitive surge peak on-state current	t _p = 10 ms		9	
l ² t	I ² t Value for fusing	t _p = 10 ms	T _j = 25 °C	0.4	A ² s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \ x \ I_{GT}$, $t_r \leq 100 \ ns$	F = 60 Hz	T _j = 125 °C	50	A/µs
I _{GM}	Peak gate current $t_p =$		T _j = 125 °C	1	Α
P _{G(AV)}	Average gate power dissipation $T_j = 125 ^{\circ}\text{C}$			0.1	W
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 125	°C

Table 2. Electrical characteristics

Symbol	Test Conditions			Value	Unit
1.			MIN.	15	^
I _{GT}	$V_D = 12 \text{ V}, R_L = 140 \Omega$		MAX.	200	μΑ
V _{GT}			MAX.	0.8	V
V _{GD}	$V_D = V_{DRM}$, $R_L = 3.3 \text{ k}\Omega$, $R_{GK} = 1 \text{ k}\Omega$	T _j = 125 °C	MIN.	0.2	V
V _{RG}	I _{RG} = 10 μA		MIN.	5	V
I _H	$I_T = 50 \text{ mA}, R_{GK} = 1 \text{ k}\Omega$		MAX.	5	mA
ΙL	$I_G = 1 \text{ mA}, R_{GK} = 1 \text{ k}\Omega$		MAX.	6	mA
dV/dt	$V_D = 67\% V_{DRM}, R_{GK} = 1 k\Omega$	T _j = 125 °C	MIN.	25	V/µs
V _{TM}	I _{TM} = 1 A, tp = 380 μs	T _j = 25 °C	MAX.	1.35	V
V _{t0}	Threshold voltage	T _j = 125 °C	MAX.	0.85	V
R _d	Dynamic resistance $T_j = 125 ^{\circ}\text{C}$		MAX.	245	mΩ
I _{DRM} I _{RRM}	V -V P -1k0	T _j = 25 °C	MAX.	1	^
	$V_{DRM} = V_{RRM}, R_{GK} = 1 k\Omega$	T _j = 125 °C	MAX.	100	μΑ

X006 Characteristics

Table 3. Thermal resistances

Symbol	Parameter			Value	Unit
R _{th(j-a)}	lunation to orghicant (DC)		TO-92	150	
	Junction to ambient (DC)	$S = 5 \text{ cm}^2$	SOT-223	60	00/14/
R _{th(j-l)}	Junction to lead (DC)		TO-92	70	°C/W
R _{th(j-t)}	Junction to tab (DC)		SOT-223	30	

Figure 1. Maximum average power dissipation versus average on-state current

Figure 2. Average and DC on-state current versus case temperature (TO-92)

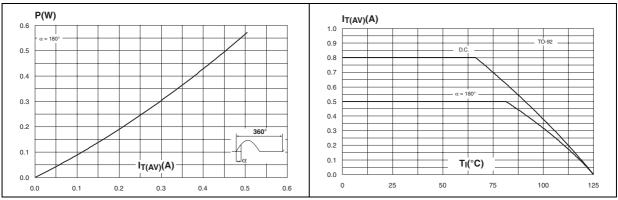
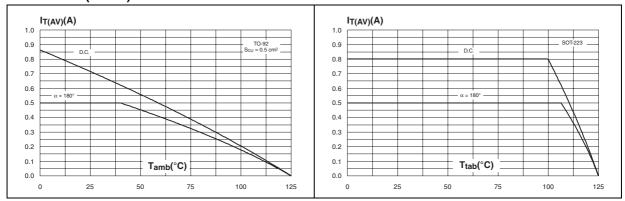


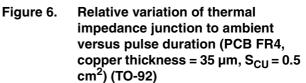
Figure 3. Average and D.C. on-state current versus ambient temperature (epoxy printed circuit board FR4, copper thickness = 35 μ m, S_{CU} = 0.5 cm²) (TO-92)

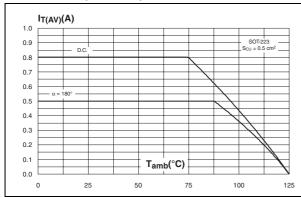
Figure 4. Average and DC on-state current versus case temperature (SOT-223)



Characteristics X006

Figure 5. Average and DC on-state current versus ambient temperature (epoxy PCB FR4, copper thickness = 35 μ m, S_{CU} = 5 cm²) (SOT-223)





2th(j-a)/Rth(j-a)

1.00

To 92

Scu = 0.5 cm²

0.10

tp(s)

1.E-03

1.E-02

1.E-01

1.E+00

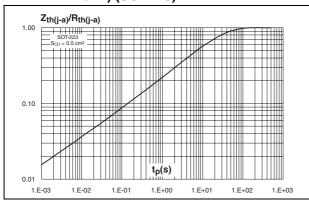
1.E+01

1.E+02

1.E+03

Figure 7. Relative variation of thermal impedance junction to ambient versus pulse duration (PCB FR4, copper thickness = $35 \mu m$, $S_{CU} = 0.5 cm^2$) (SOT-223)

Figure 8. Thermal resistance junction to ambient versus copper surface under tab (PCB FR4, copper thickness = 35 µm) (SOT-223)



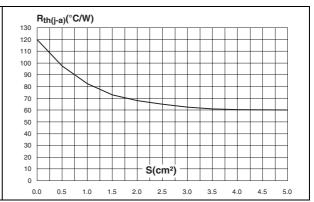
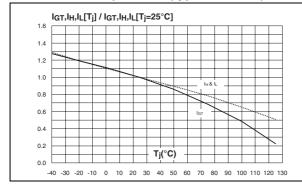
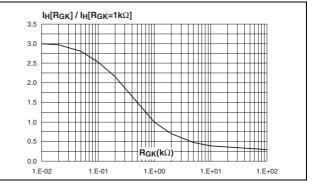


Figure 9. Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)

Figure 10. Relative variation of holding current versus gate-cathode resistance (typical values)





5

X006 Characteristics

Figure 11. Relative variation of dV/dt immunity Figure 12. Relative variation of dV/dt immunity versus gate-cathode resistance (typical values)

Relative variation of dV/dt immunity versus gate-cathode capacitance (typical values)

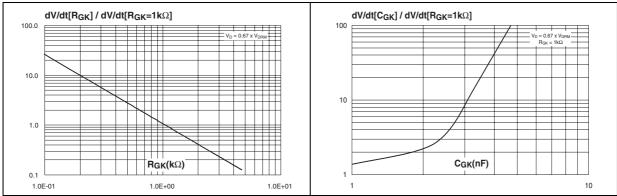


Figure 13. Surge peak on-state current versus Figure 14. Non repetitive surge peak on-state number of cycles current for a sinusoidal pulse with

Non repetitive surge peak on-state current for a sinusoidal pulse with width t_{p} < 10ms, and corresponding value of $l^{2}t$

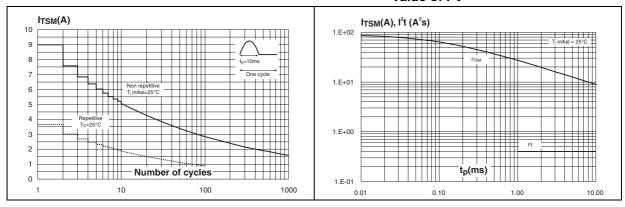
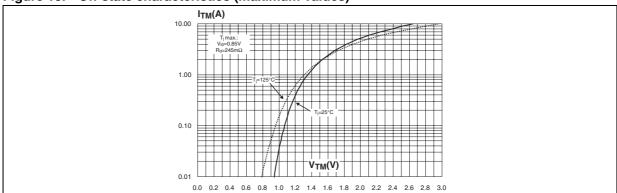


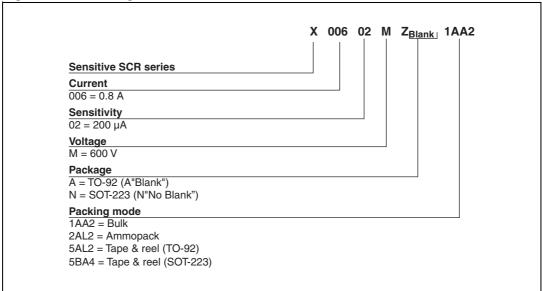
Figure 15. On-state characteristics (maximum values)



5/

2 Ordering information scheme

Figure 16. Ordering information scheme



X006 Package information

3 Package information

Epoxy meets UL94, V0

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at www.st.com.

Table 4. TO-92 (plastic) dimensions

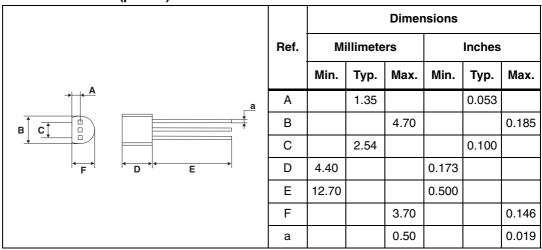
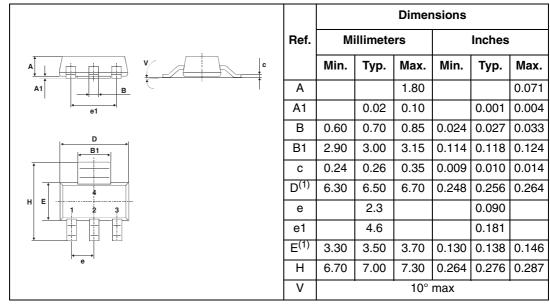


Table 5. SOT-223 dimensions



^{1.} Do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm (0.006inches)

Ordering information X006

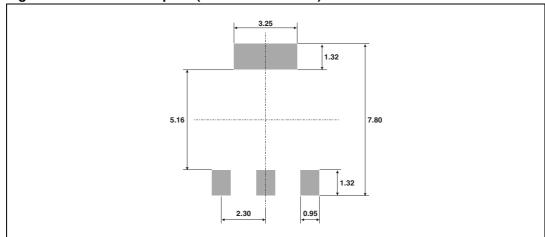


Figure 17. SOT-223 footprint (dimensions in mm)t

4 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
X00602MA 1AA2				2500	Bulk
X00602MA 2AL2	X0602 MA	TO-92	0.2 g	2000	Ammopack
X00602MA 5AL2				2000	Tape and reel
X00602MN5BA4	X06 2M	SOT-223	0.12 g	1000	Tape and Teel

5 Revision history

Table 7. Document revision history

Date	Revision	Changes
Jan-2002	3	Last update.
08-Aug-2006	4	SOT-223 package added.
1-Apr-2008	5	Reformatted to current standards. Device X00605 removed. Updated dimensions in <i>Table 5</i> .

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2008 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

